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In re Patent Application of

SUGIHARA ET AL.

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For:

SEMICONDUCTOR DEVICE, MANUFACTURING

METHOD THEREOF, AND ELECTRONIC DEVICE

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

Sir:

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Further to applicants' Information Disclosure Statement of July 26, 2006, applicants herewith submit a corrected Form PTO-1449 (i.e., the date of the second article (Carcia et al reference) has been corrected).

Respectfully submitted,

NIXON & VANDERHYE P.C.

September 11, 2006

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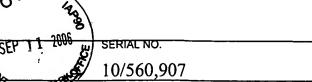
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Sheet of 1

INFORMATION DISCLOSURE **CITATION**

ATTY. DOCKET NO.

1035-616 APPLICANT



(Use several sheets if necessary)

SUGIHARA ET AL FILING DATE

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Form PTO-FB-A820 (Also PTO-1449)